IFW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

DCT 1 4: 2004

Applicant(s): MAMITSU et al.

Serial No.: 10/699,837

Filed: November 4, 2003

Title: SEMICONDUCTOR DEVICE HAVING

RADIATION STRUCTURE

Atty. Dkt.: 01-103-CON3

Group Art Unit: 2822

Examiner: Unknown

Commissioner for Patents Arlington, VA 22202

Date: October 14, 2004

INFORMATION DISCLOSURE STATEMENT

Sir:

Pursuant to 37 C.F.R. §1.56, the references listed on the attached Form PTO-1449 are being submitted for consideration by the Examiner without any admission that they constitute statutory prior art, or without any admission that they contain subject matter that anticipates the invention or renders the invention obvious to a person of ordinary skill in the art.

Further, pursuant to 37 C.F.R. §1.97(e)(1), the undersigned hereby certifies that each listed reference was first cited in a Communication (copy enclosed) from a foreign patent office in connection with a counterpart foreign application not more than three months prior to the filing of this statement.

Although no fees are believed to be due at this time, it is respectfully requested that any such fees be charged to Deposit Account 50-1147. Also, the Examiner is requested to initial the attached PTO Form-1449 and to return a copy of same to the undersigned attorney as proof that the listed references have been considered and made of record.

Respectfully submitted,

David G. Posz Reg. No. 37,701

Posz & Bethards, PLC 11250 Roger Bacon Drive Suite 10 Reston, VA 20190 (703) 707-9110 (phone) Customer No. 23400

PATENT APPLICATION

OIPE				Page 1 of 1
FORM PTO-1/49	ATTY. DKT NO.	01-103-CON3	SER. NO.	10/699,837
OCT 1 4 2004 💆	APPLICANT	MAMITSU et al.		
	FILING DATE	November 4, 2003	GROUP	2822

EFERENCE DESIGNATION U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
		:			

FOREIGN PATENT DOCUMENTS

TRANSLATION

						110777	ISLATION
DOCUMENT NUMBER	DATE	COUNTRY	NAME	CLASS	SUB CLASS	YES	NO (Abstract)
JP-A-H07-66143	3/10/95	JAPAN					Х
JP-A-H09-237868	9/9/97	JAPAN					х
JP-A-H09-45773	2/14/97	JAPAN					х
JP-A-H11-204803	7/30/99	JAPAN					X

^{*} Full English text of the JP Document will be available in machine-translated form from JP (Japanese Patent Office) English language web site at http://www1.ipdl.jpo.go.jp/PA1/cgi-bin/PA1INDEX.

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

EXAMINER		DATE CONSIDERED

Rev. 10/94 (Form 3.05)